

MOSFET Maximum Ratings $T_A = 25 \degree C$ unless otherwise noted

Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			150	V	
V _{GS}	Gate to Source Voltage			±20	V	
ID	Drain Current -Continuous			4.5	•	
	-Pulsed			20	Α	
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	60	mJ	
D	Power Dissipation	T _A = 25 °C	(Note 1)	5.0	W	
PD	Power Dissipation	T _A = 25 °C	(Note 1a)	2.5	vv	
T _J , T _{STG}	Operating and Storage Junction Temperature Ra	inge		-55 to +150	°C	

Thermal Characteristics

R_{\thetaJC}	Thermal Resistance, Junction to Case	(Note 1)	25	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	50	C/vv

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDS86252	FDS86252	SO-8	13 "	12 mm	2500 units

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	$I_{D} = 250 \ \mu A, \ V_{GS} = 0 \ V$	150			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25 °C		103		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 120 V, V _{GS} = 0 V			1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA
On Chara	cteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 250 \ \mu A$	2	3.4	4	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25 °C		-11		mV/°C
r _{DS(on)}	Static Drain to Source On Resistance	V _{GS} = 10 V, I _D = 4.5 A	45 55			
		$V_{GS} = 6 \text{ V}, \text{ I}_{D} = 3.7 \text{ A}$		57	80	mΩ
		V_{GS} = 10 V, I _D = 4.5 A, T _J = 125 °C		86	105	
9 _{FS}	Forward Transconductance	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 4.5 \text{ A}$		13		S
Dynamic	Characteristics					
Ciss	Input Capacitance	V 75.V.V 0.V		718	955	pF
C _{oss}	Output Capacitance	V _{DS} = 75 V, V _{GS} = 0 V, f = 1 MHz		77	105	pF
C _{rss}	Reverse Transfer Capacitance			3.3	5	pF
Rg	Gate Resistance			0.6		Ω
Switching	g Characteristics					
t _{d(on)}	Turn-On Delay Time			9.2	19	ns
t _r	Rise Time	V _{DD} = 75 V, I _D = 4.5 A,		1.6	10	ns
t _{d(off)}	Turn-Off Delay Time	V_{GS} = 10 V, R_{GEN} = 6 Ω		14	24	ns
t _f	Fall Time			2.9	10	ns
0	Total Gate Charge	$V_{GS} = 0 V \text{ to } 10 V$		10.6	15	nC
Q _{g(TOT)}	Total Gate Charge	$V_{GS} = 0 \text{ V to 5 V}$ $V_{DD} = 75 \text{ V}$		5.2	9	nC
Q _{gs}	Total Gate Charge	I _D = 4.5 A		3.5		nC

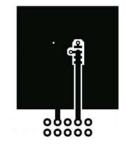
Total Gate Charge Gate to Drain "Miller" Charge Q_{gd}

Drain-Source Diode Characteristics

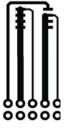
V	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 4.5 A$ (Note 2)	0.80	1.3	V
V _{SD}	Source to Brain Blode Torward Voltage	$V_{GS} = 0 V, I_S = 2 A$ (Note 2)	0.76	1.2	
t _{rr}	Reverse Recovery Time	I _E = 4.5 A, di/dt = 100 A/μs 60 95		ns	
Q _{rr}	Reverse Recovery Charge	$F = 4.5 \text{ A}, \text{ u/ut} = 100 \text{ A/}\mu\text{S}$	74	118	nC

NOTES:

1. R_{0,JA} is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{0,JC} is guaranteed by design while R_{0CA} is determined by the user's board design.



a) 50 °C/W when mounted on a 1 in² pad of 2 oz copper.



b) 125 °C/W when mounted on a minimum pad.

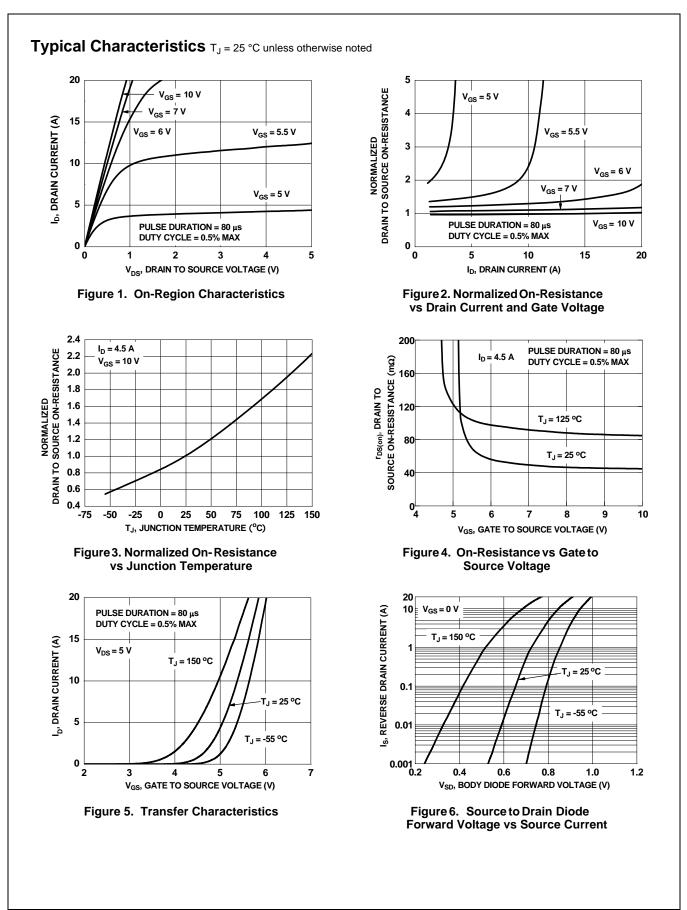
2.3

2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty cycle < 2.0 %.

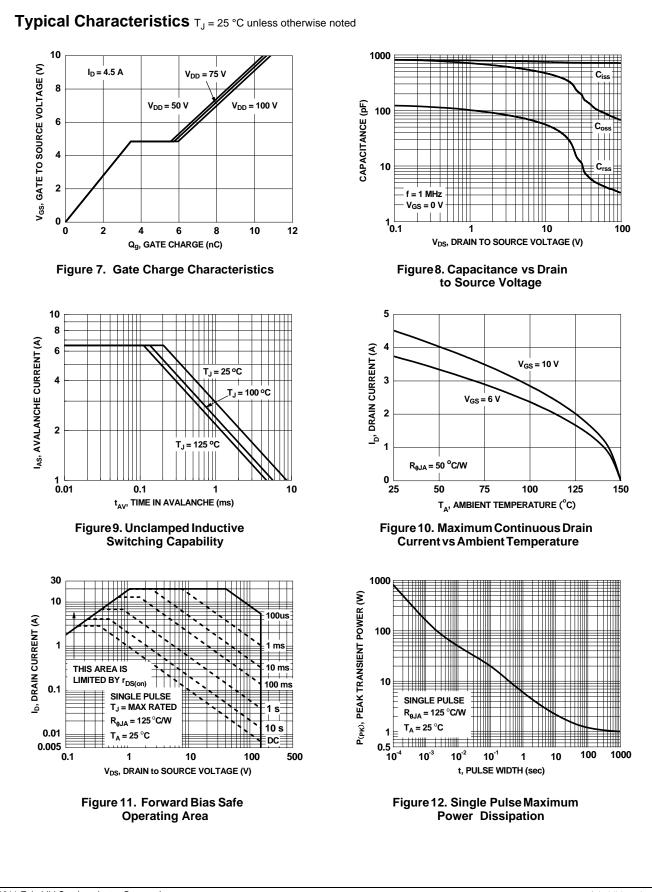
3. Starting T_J = 25 $^oC;$ N-ch: L = 1 mH, I_{AS} = 11 A, V_{DD} = 135 V, V_{GS} = 10 V.

nC

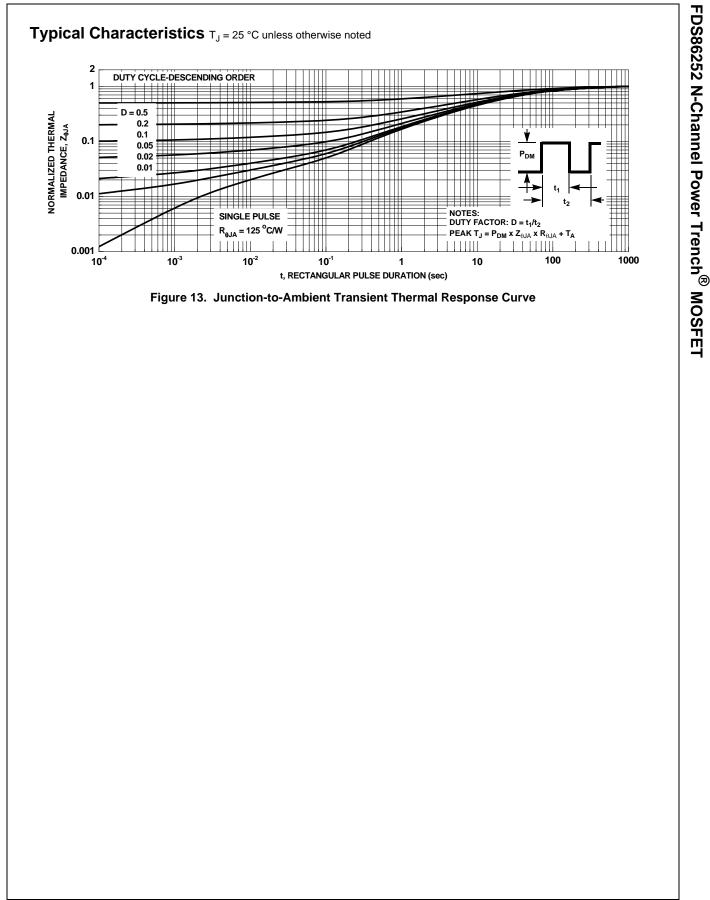
FDS86252 N-Channel Power Trench[®] MOSFET



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